

Chip Integration Technology Corporation

Super Low Barrier High Voltage Power Rectifier

Main Product Characteristics

I _{F(AV)}	5A		
V _{RRM}	100V		
T,	150°C		
$V_{(Typ)}$	0.53V		

■ Features

- Low forward voltage drop.
- Excellent high temperature stability.
- · Fast switching capability.
- Suffix "G" indicates Halogen-free part, ex.CSP5L100SG-A.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

■ Mechanical data

• Epoxy: UL94-V0 rated flame retardant.

• Case: Molded plastic, TO-277.

 Lead: Solder plated, solderable per MIL-STD-750, Method 2026.

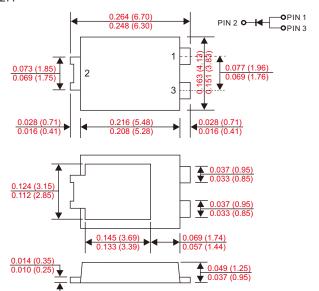
• Polarity: Indicated by cathode band.

• Mounting Position : Any.

• Weight : Approximated 0.093 grams.

■ Outline





Dimensions in inches and (millimeters)

■ Maximum ratings and electrical characteristics

Rating at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

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Parameter	Conditions	Symbol	CSP5L100S-A	LINUT	
Marking code			CSP5L100S	UNIT	
Peak repetitive reverse voltage		V _{RRM}			
Working peak reverse voltage		V_{RWM}	100	V	
DC blocking voltage		V _{RM}			
Forward rectified current		Io	5	Α	
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}	200	А	
Thermal resistance	Junction to case	R _{eJC}	6	°C/W	
Operating and Storage temperature		T _J , T _{STG}	-55 ~ +150	°C	

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward voltage drop	$I_F = 5A, T_J = 25^{\circ}C$	V			720	mV
	I _F = 5A, T _J = 125°C	V _F		530	600	
Reverse current	$V_R = V_{RRM} T_J = 25^{\circ}C$				0.1	mA
	$V_R = V_{RRM} T_J = 125^{\circ}C$	I _R			100	

Note: 1.Theoretical R0JS calculated from the top center of the die straight down to the PCB cathode tab solder junction. 2.Polymide PCB, 2oz.Copper.

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■ Rating and characteristic curves

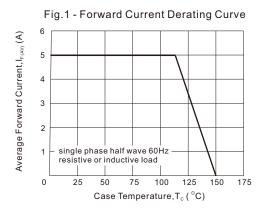


Fig. 2 - Instantaneous Forward Characteristics

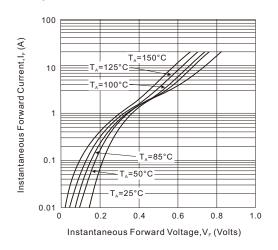
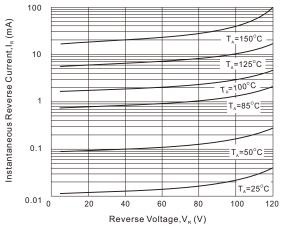


Fig. 3 - Reverse Characteristics



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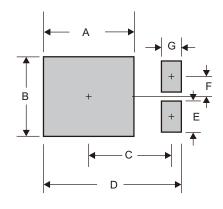
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■ TO-277 foot print



Α	В	С	D	Е	F	G
0.185 (4.70)	0.142 (3.60)	0.152 (3.87)	0.260 (6.60)	0.055 (1.40)	0.035 (0.90)	0.031 (0.80)

Dimensions in inches and (millimeters)

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http://www.citcorp.com.tw/

Tel:886-3-5600628

Fax:886-3-5600636

Add:Rm. 3, 2F., No.32, Taiyuan St., Zhubei City, Hsinchu County 302, Taiwan (R.O.C.)

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